

MCP75N120S2C3

V_{CE}	$I_{c\ nom}$
1200V	75A

C3


DESCRIPTION

The MCP75N120S2C3 module with JSCJ advanced Trench and FS (Field Stop) IGBT provide very low Collector-Emitter Saturation Voltage, easy to use in drives and inverters.

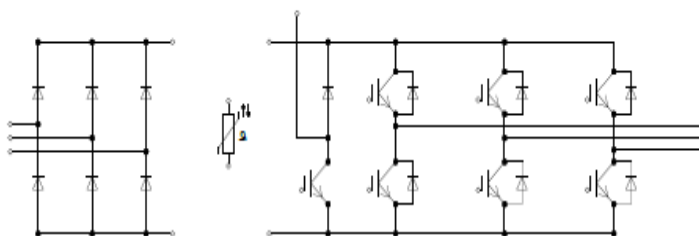
Features

- $T_{vj\ op} = 150^{\circ}\ C$
- Low $V_{ce(sat)}$ and positive temperature coefficient
- Low switching loss
- Standard housing
- Solder contact technology

Application

- Servo drives
- Medical applications
- Motor drives
- Auxiliary inverters

EQUIVALENT CIRCUIT



Order Code	Package	Marking	Parking
MCP75N120S2C3	C3	MCP75N120S2C3	Module



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

IGBT Discrets & Modules

感谢您的支持，如需要完整规格书，请联系：<igbt.list@jscj-elec.com>，谢谢！

Thank you for your support. If you need a complete datasheet, please contact:

<igbt.list@jscj-elec.com>. Thank you!